# RICOH

# RP602x Series

# 1.5 A PWM/VFM Buck-Boost DC/DC Converter with Synchronous Rectifier

No. EA-353-190507

### OVERVIEW

The RP602x is a 6.5 V (Max. rating) buck-boost DC/DC converter with synchronous rectifier. This device is ideally suited for industrial or OA equipment that require constant voltage even when low-input voltage (Min. 2.3 V). Since operating with switching frequency of 2.6 MHz, this device can realize a high-speed response with a small coil and maintain a high-efficiency at low input voltage.

#### **KEY BENEFITS**

- Realize a high-efficiency at low input voltage.
- Provide output voltage of 2.7 to 4.2 V corresponding to input voltage of 2.3 to 5.5 V.

#### KEYSPECIFICATIONS

- Input Voltage Range: 2.3 V to 5.5 V
- Output Voltage Range: 2.7 V to 4.2 V (0.1V step)
- Output Voltage Accuracy :±1.5%
- Line Regulation: Typ. 0.5%, PWM mode
- Load Regulation: Typ. 0.1%,

 $(I_{OUT} = 0 \text{ to } 500 \text{ mA}, PWM \text{ mode})$ 

- Maximum Output Current: Typ. 1.5 A, (PVIN = 3 V, VOUT = 3.3 V)
- Maximum Burst Current: Typ. 2.7 A, (PVIN=3 V, VOUT=3.3 V, Duty=10%, t=2.0 ms)
- Overcurrent Limit Protection: Typ. 4.2 A
- Oscillator Frequency: Typ. 2.6 MHz
- Built-in Driver ON Resistance:

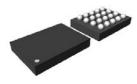
Typ. Pch. 80 m $\Omega$ , Nch. 80 m $\Omega$ 

- Operating Quiescent Current: Typ. 27.5 μA,
  - (VFM mode, Non-switching)
    UVLO Detector Threshold: Typ. 2.0 V
- Soft-start Time: Typ. 1.0 ms
- Thermal Shutdown Temperature:Typ.150°C
- Protection Feature: Overvoltage, Overcurrent

#### **PACKAGE**

RP602Z

RP602K

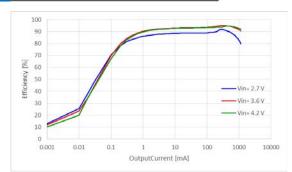


WLCSP-20-P1 2.305 mm x 1.700 mm



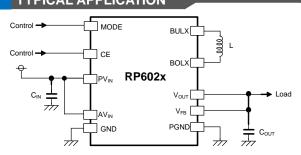
DFN(PLP)2730-12 2.7mm × 3.0mm

## **TYPICAL CHARACTERISTICS**



Efficiency Characterisitcs (RP602Z330x, MODE = H)

# TYPICAL APPLICATION



#### **OPTIONAL FUNCTION**

The following functions are user-selectable options.

Code	Auto-discharge Function	Latch Protection	Reset Protection
A/E	Yes	Yes	No
B/F	No	Yes	No
C/G	Yes	No	Yes
D/H	No	No	Yes

#### **APPLICATIONS**

- Power source for portable equipment such as laptops, PDAs, DSCs, cellular phones, and smartphones
- Power source for Li-ion battery-used equipment

No. JA-353-190507

# **SELECTION GUIDE**

# **Selection Guide**

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP602Zxxx\$-E2-F	WLCSP-20-P1	5,000 pcs	Yes	Yes
RP602Kxxx#-TR	DFN(PLP)2730-12	5,000 pcs	Yes	Yes

xxx: Specify the set output voltage ( $V_{\text{SET}}$ ) within the range of 2.7 V to 4.2 V in 0.1 V  $^{(1)}$  steps.

\$: Specify the combination of the auto-discharge option and the protection function option.

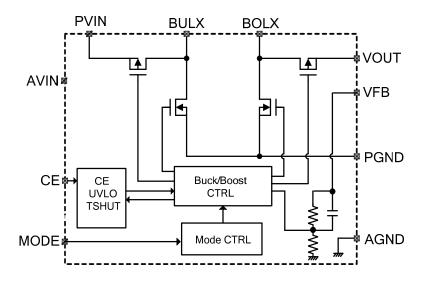
Symbol	Auto-discharge Function	Latch-type Protection	Reset-type Protection	Short-circuit Protection
Α	Yes	Yes	No	Yes
В	No	Yes	No	Yes
С	Yes	No	Yes	Yes
D	No	No	Yes	Yes

#: Specify the combination of the auto-discharge option and the protection function option.

Symbol	Auto-discharge Function	Latch-type Protection	Reset-type Protection	Short-circuit Protection
E	Yes	Yes	No	Yes
F	No	Yes	No	Yes
G	Yes	No	Yes	Yes
Н	No	No	Yes	Yes

<sup>&</sup>lt;sup>(1)</sup> 0.05 V step is also available as a custom code.

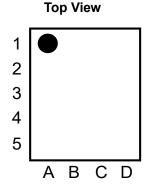
# **BLOCK DIAGRAM**

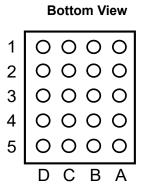


RP602x Block Diagram

# PIN DESCRIPTION

# **RP602Z Pin Description**





WLCSP-20-P1 Pin Configuration

Pin No.	Symbol	Pin Description
A5, B5, C5	VOUT (1)	Output Voltage Pin
A4, B4, C4	BOLX (1)	Boost Switching Output Pin
A3, B3, C3	PGND (2)	Power GND Pin
A2, B2, C2	BULX (1)	Buck Switching Output Pin
A1, B1, C1	PVIN (1)	Power Input Voltage Pin
D1	AVIN (1)	Analog Power Input Voltage Pin
D2	CE	Chip Enable Pin, Active-high
D3	MODE	Mode Control Pin, Forced PWM Control: L, PWM/VFM Auto Switching Control: H
D4	AGND (2)	Analog GND Pin
D5	VFB	Output Voltage Feedback Pin

#### **Pin Truth Table**

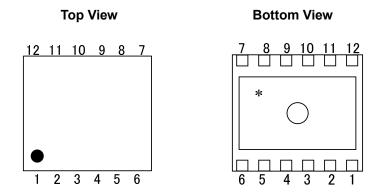
CE Pin	MODE Pin (3)	Operation
L	-	OFF
	Н	PWM/ VFM Auto Switching Control Mode
Н	L	Forced PWM Control Mode

<sup>(1)</sup> The pin numbers sharing the same pin symbol must be connected together: A4, B4, and C4 of the BOLX pin, A2, B2, and C2 of the BULX pin, A5, B5, and C5 of the VOUT pin. D1 of the AVIN pin and A1, B1, and C1 of the PVIN pin must be connected together.

<sup>(2)</sup> D4 of the AGND pin and A3, B3, and C3 of the PGND pin must be connected to the ground.

<sup>(3)</sup> The logic to the MODE pin should not be changed while CE = "H".

# **RP602K Pin Description**



# DFN(PLP)2730-12 Pin Configuration

Pin No.	Symbol	Pin Description
1	AVIN (1)	Analog Power Input Voltage Pin
2	CE	Chip Enable Pin, Active-high
3	MODE	Mode Control Pin, Forced PWM Control: L, PWM/VFM Auto Switching Control: H
4	NC	No Connection
5	AGND (2)	Analog GND Pin
6	VFB	Output Voltage Feedback Pin
7	VOUT	Output Voltage Pin
8	BOLX	Boost Switching Output Pin
9,10	PGND (2)	Power GND Pin
11	BULX	Buck Switching Output Pin
12	PVIN (1)	Power Input Voltage Pin

<sup>\*</sup> The tab on the bottom of the package must be connected to the ground plane on the board to enhance thermal performance.

#### **Pin Truth Table**

CE Pin MODE Pin (3) Operation			
L	-	OFF	
Ш	Н	PWM/ VFM Auto Switching Control Mode	
Н	L	Forced PWM Control Mode	

<sup>&</sup>lt;sup>(1)</sup> The AVIN pin and the PVIN pin must be connected together.

 $<sup>^{\</sup>left(2\right)}$  The AGND pin and the PGND pin must be connected to the ground.

<sup>(3)</sup> The logic to the MODE pin should not be changed while CE = "H".

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# **ABSOLUTE MAXIMUM RATINGS**

Absolute Maximum Ratings

(AGND = PGND = 0 V)

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Symbol		Item	Rating	Unit
$V_{IN}$	AVIN/ PVIN Pin Voltage	9	-0.3 to 6.5	V
V <sub>BULX</sub>	BULX Pin Voltage		-0.3 to V <sub>IN</sub> + 0.3	V
V <sub>BOLX</sub>	BOLX Pin Voltage		-0.3 to V <sub>OUT</sub> + 0.3	V
V <sub>CE</sub>	CE Pin Voltage		-0.3 to 6.5	V
V <sub>MODE</sub>	MODE Pin Voltage		-0.3 to 6.5	V
Vouт	VOUT Pin Voltage		-0.3 to 6.5	V
$V_{FB}$	VFB Pin Voltage	VFB Pin Voltage		V
I <sub>LX</sub>	BULX/ BOLX Pin Outpu	it Current	4.2	Α
D-	Power Dissipation (1)	WLCSP-20-P1 (JEDEC STD.51-9)	1400	m\\/
P <sub>D</sub>		DFN(PLP)2730-12 (JEDEC STD.51-7)	3100	mW
Tj	Junction Temperature F	Junction Temperature Range		°C
Tstg	Storage Temperature R	ange	-55 to 125	°C
	•			

### **ABSOLUTE MAXIMUM RATINGS**

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings are not assured.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
VIN	Input Voltage	2.3 to 5.5	V
Та	Operating Temperature Range	-40 to 85	°C

### **RECOMMENDED OPERATING CONDITIONS**

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such ratings by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

<sup>(1)</sup> Refer to POWER DISSIPATION for detailed information.

# **ELECTRICAL CHARACTERISTICS**

Open-loop Measurement GND = 0 V, unless otherwise noted.

**RP602Z Electrical Characteristics** 

(Ta = 25°C)

RP602Z	Z Electrical Characteristics (1a = 25)					25°C)	
Symbol	Item	Cond	itions	Min.	Тур.	Max.	Unit
	Power Current	$V_{IN} = 5.5 V$	V <sub>MODE</sub> = 5.5V		27.5	60	_
I <sub>DD</sub>		V <sub>OUT</sub> = 4.2 V	V <sub>MODE</sub> = 0 V		1000	1400	μΑ
ISTANDBY	Standby Current	V <sub>IN</sub> = 5.5 V, V	/ <sub>CE</sub> = 0 V		0.1	5.0	μΑ
Vоит	Output Voltage	V <sub>IN</sub> = 3.6 V		x0.985		x1.015	V
Δ V <sub>OUT</sub> /ΔTa	Output Voltage Temperature Coefficient	-40°C ≤ Ta ≤	≨ 85°C		±50		ppm/ °C
Vove	OVP Detection Voltage	V <sub>IN</sub> = 3.6 V ,	Rising	4.5	5.0	5.5	٧
VOVP	OVP Release Voltage	V <sub>IN</sub> = 3.6 V ,	Falling	4.3	4.8	5.3	٧
fosc	Switching Frequency	V <sub>IN</sub> = 3.6 V		2.4	2.6	2.9	MHz
Інмня	BULX Current Limit (1)	V <sub>IN</sub> = 3.6 V		3.7	4.2		Α
Ron	High & Low Switch On-resistance	V <sub>IN</sub> = 3.6 V			80		mΩ
R <sub>DIS</sub>	On-resistance of Discharge Tr. (RP602ZxxxA/C)	V <sub>IN</sub> = 3.6 V, V	/ <sub>CE</sub> = 0 V		80		Ω
I <sub>FBH</sub>	V <sub>FB</sub> Input Current, High	V <sub>IN</sub> = 5.5 V, V <sub>CE</sub> = 0 V V <sub>FB</sub> = 5.5V				1	μA
I <sub>FBL</sub>	V <sub>FB</sub> Input Current, Low	$V_{IN} = 5.5 \text{ V}, \text{ V}$ $V_{FB} = 0 \text{ V}$	/ <sub>CE</sub> = 0 V			1	μA
V <sub>H</sub>	CE / MODE Pins Input Voltage, High	V <sub>IN</sub> = 5.5 V		1.0			V
VL	CE / MODE Pins Input Voltage, Low	V <sub>IN</sub> = 2.3 V				0.4	٧
Ін	CE / MODE Pins Input Current, High	V <sub>IN</sub> = V <sub>CE</sub> = 5	.5 V	-1	0	1	μΑ
IL	CE / MODE Pins Input Current, Low	V <sub>IN</sub> = 5.5 V, V	/ <sub>CE</sub> = 0 V	-1	0	1	μΑ
V <sub>UVLO1</sub>	UVLO Detection Voltage	V <sub>IN</sub> = Falling		1.83	2.00		V
V <sub>UVLO2</sub>	UVLO Release Voltage	V <sub>IN</sub> = Rising			2.05	2.25	V
T <sub>TSD</sub>	Thermal Shutdown Threshold	Tj, Rising			150		°C
T <sub>TSR</sub>	Temperature	Tj, Falling			110		°C
tstart	Soft-start Time	V <sub>IN</sub> = 3.6 V			1		ms
<b>t</b> PROT	Protection Delay Time (RP602ZxxxA/B/C/D)	V <sub>IN</sub> = 3.6 V			1.6		ms
t <sub>RST</sub>	Reset Protection Delay Time (RP602ZxxxC/D)	V <sub>IN</sub> = 3.6 V			12		ms

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition (Tj ≈ Ta = 25°C).

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<sup>(1)</sup> BULX Current Limit vary according to the switching duty ratio.

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Open-loop Measurement GND = 0 V, unless otherwise noted.

### **RP602K Electrical Characteristics**

(Ta = 25°C)

NF 002N Electrical Characteristics				(10	1 - 23 C)		
Symbol	Item	Cond	itions	Min.	Тур.	Max.	Unit
	D	V <sub>IN</sub> = 5.5 V,	V <sub>MODE</sub> = 5.5 V		27.5	60	^
I <sub>DD</sub>	Power Current	$V_{OUT} = 4.2 \text{ V},$	V <sub>MODE</sub> = 0 V		1000	1400	μA
ISTANDBY	Standby Current	V <sub>IN</sub> = 5.5 V, V <sub>O</sub>	ce = 0 V		0.1	5.0	μA
V <sub>OUT</sub>	Output Voltage	V <sub>IN</sub> = 3.6 V		x0.985		x1.015	V
Δ V <sub>О∪Т</sub> /ΔTa	Output Voltage Temperature Coefficient	-40°C ≤ Ta ≤ 8	85°C		±50		ppm/ °C
Vove	OVP Detection Voltage	V <sub>IN</sub> = 3.6 V , R	ising	4.5	5.0	5.5	V
VOVP	OVP release Voltage	V <sub>IN</sub> = 3.6 V , F	alling	4.3	4.8	5.3	V
fosc	Switching Frequency	V <sub>IN</sub> = 3.6 V		2.4	2.6	2.9	MHz
ILIMHS	BULX Current Limit (1)	V <sub>IN</sub> = 3.6 V		3.7	4.2		Α
Ron	High & Low Switch On-resistance	V <sub>IN</sub> = 3.6 V			120		mΩ
R <sub>DIS</sub>	On-resistance of Discharge Tr. (RP602KxxxE/G)	V <sub>IN</sub> = 3.6 V, V <sub>O</sub>	ce = 0 V		80		Ω
I <sub>FBH</sub>	V <sub>FB</sub> Input Current, High	$V_{IN} = 5.5 \text{ V}, V_{CE} = 0 \text{ V}$ $V_{FB} = 5.5 \text{V}$				1	μA
I <sub>FBL</sub>	V <sub>FB</sub> Input Current, Low	$V_{IN} = 5.5 \text{ V}, V_{CE} = 0 \text{ V}$ $V_{FB} = 0 \text{ V}$				1	μA
Vн	CE / MODE Pins Input Voltage, High	V <sub>IN</sub> = 5.5 V		1.0			٧
VL	CE / MODE Pins Input Voltage, Low	V <sub>IN</sub> = 2.3 V				0.4	٧
lн	CE / MODE Pins Input Current, High	V <sub>IN</sub> = V <sub>CE</sub> = 5.5	5 V	-1	0	1	μA
IL	CE / MODE Pins Input Current, Low	V <sub>IN</sub> = 5.5 V, V <sub>C</sub>	ce = 0 V	-1	0	1	μA
V <sub>UVLO1</sub>	UVLO Detection Voltage	V <sub>IN</sub> = Falling		1.83	2.00		V
V <sub>UVLO2</sub>	UVLO Release Voltage	V <sub>IN</sub> = Rising			2.05	2.25	V
T <sub>TSD</sub>	Thermal Shutdown Threshold	Tj, Rising			150		°C
T <sub>TSR</sub>	Temperature	Tj, Falling			110		°C
tstart	Soft-start Time	V <sub>IN</sub> = 3.6 V			1		ms
<b>t</b> PROT	Protection Delay Time (RP602KxxxE/F/G/H)	V <sub>IN</sub> = 3.6 V			1.6		ms
t <sub>RST</sub>	Reset Protection Delay Time (RP602KxxxG/H)	V <sub>IN</sub> = 3.6 V			12		ms

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition ( $Tj \approx Ta = 25$ °C).

<sup>(1)</sup> BULX Current Limit vary according to the switching duty ratio.

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**Product-specific Electrical Characteristics** 

(Ta = 25°C)

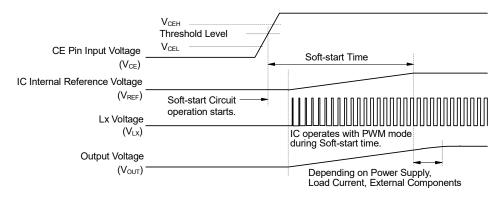
Due de et Nome	Vout (V)		
Product Name	Min.	Тур.	Max.
RP602x270x	2.660	2.700	2.740
RP602x280x	2.758	2.800	2.842
RP602x290x	2.857	2.900	2.943
RP602x300x	2.955	3.000	3.045
RP602x310x	3.054	3.100	3.146
RP602x320x	3.152	3.200	3.248
RP602x330x	3.251	3.300	3.349
RP602x340x	3.349	3.400	3.451
RP602x350x	3.448	3.500	3.552
RP602x360x	3.546	3.600	3.654
RP602x370x	3.645	3.700	3.755
RP602x380x	3.743	3.800	3.857
RP602x390x	3.842	3.900	3.958
RP602x400x	3.940	4.000	4.060
RP602x410x	4.039	4.100	4.161
RP602x420x	4.137	4.200	4.263

### THEORY OF OPERATION

#### **Soft-start Time**

#### Starting-up with CE Pin

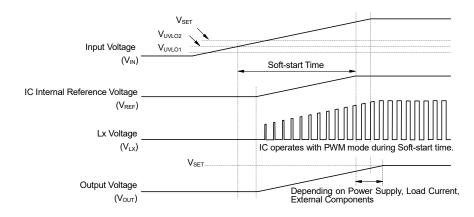
The IC starts to operate when the CE pin voltage ( $V_{CE}$ ) exceeds the threshold voltage. The threshold voltage is preset between CE "High" input voltage ( $V_{CEH}$ ) and CE "Low" input voltage ( $V_{CEL}$ ). After the start-up of the IC, soft-start circuit starts to operate. Then, after a certain period of time, the reference voltage ( $V_{REF}$ ) in the IC gradually increases up to the specified value. Soft-start time ( $t_{START}$ ) starts when soft-start circuit is activated, and ends when the reference voltage reaches the specified voltage. Soft start time is not always equal to the turn-on speed of the DC/DC converter. Note that the turn-on speed could be affected by the power supply capacity, the output current, the inductance value and the  $C_{OUT}$  value.



Timing Chart: Starting-up with CE Pin

#### Starting-up with Power Supply

After the power-on, when  $V_{IN}$  exceeds the UVLO release voltage ( $V_{UVLO2}$ ), the IC starts to operate. Then, soft-start circuit starts to operate and after a certain period of time,  $V_{REF}$  gradually increases up to the specified value. Soft-start time starts when soft-start circuit is activated, and ends when  $V_{REF}$  reaches the specified voltage. Note that the turn-on speed of  $V_{OUT}$  could be affected by the power supply capacity, the output current, the inductance value, the  $C_{OUT}$  value and the turn-on speed of  $V_{IN}$  determined by  $C_{IN}$ .



**Timing Chart: Starting-up with Power Supply** 

#### **Undervoltage Lockout (UVLO) Circuit**

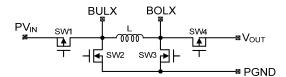
If the  $V_{IN}$  becomes lower than the UVLO detection voltage ( $V_{UVLO1}$ ), the UVLO circuit starts to operate,  $V_{REF}$  stops, and P-channel and N-channel built-in switch transistors turn "OFF". As a result,  $V_{OUT}$  drops according to the  $C_{OUT}$  capacitance value and the load. To restart the operation,  $V_{IN}$  needs to be higher than  $V_{UVLO2}$ .

## **Overvoltage Protection (OVP) Circuit**

If the  $V_{\text{OUT}}$  becomes higher than the OVP detection voltage ( $V_{\text{OVP}}$ ), the OVP circuit starts to operate, P-channel and N-channel built-in switch transistors turn "OFF". As a result,  $V_{\text{OUT}}$  drops according to the  $C_{\text{OUT}}$  capacitance value and the load.

#### **Overcurrent Protection Circuit**

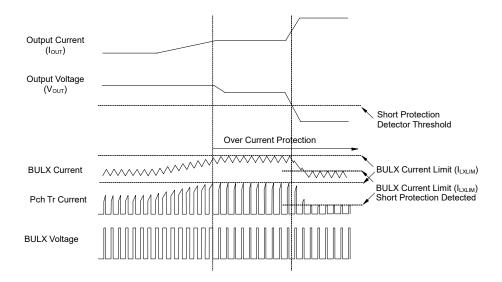
Overcurrent protection circuit supervises the inductor peak current (the peak current flowing through Pch Tr (SW1) in each switching cycle, and if the current exceeds the BULX current limit (I<sub>LXLIM</sub>), it turns off Pch Tr (SW1). I<sub>LXLIM</sub> of the RP602x is set to Typ.4200 mA.



**Simplified Diagram of Output Switches** 

#### **Short Protection Circuit**

If the  $V_{\text{OUT}}$  becomes lower than a certain threshold, the BULX current limit is reduced.

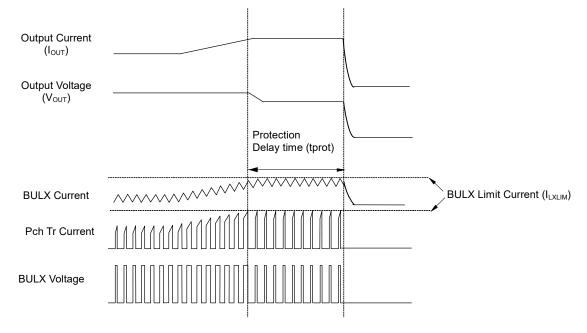


Timing Chart: Overcurrent Protection Circuit & Short Protection Circuit

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# Latch Type Protection Circuit: RP602xxxxA/B/E/F

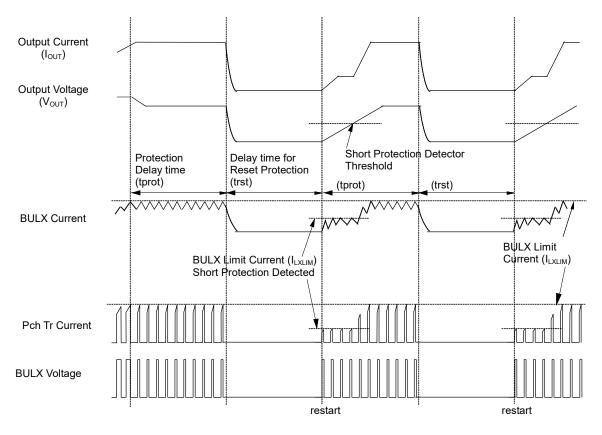
The latch type protection circuit latches the built-in drivers of SW1, SW2, SW3 and SW4 off to stop the operation of the device if the overcurrent state continues more than the protection delay time (tprot). To release the latch-type protection, reset the device by switching the CE pin from High to Low or making the input voltage (V<sub>IN</sub>) lower than the UVLO detection voltage (V<sub>UVLO1</sub>).



Timing Chart: RP602xxxxA/B/E/F Latch Protection Circuit

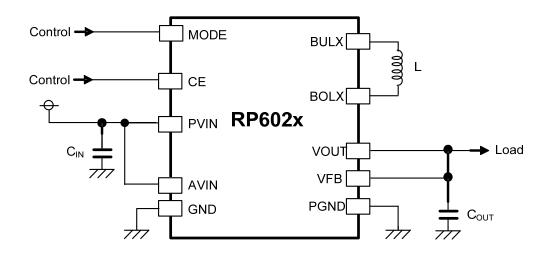
# Reset Type Protection Circuit: RP602xxxxC/D/G/H

When the overcurrent state continues more than the protection delay time (tprot), the reset type protection circuit operates and switching stops. The built-in drivers of SW1, SW2, SW3 and SW4 turn off and restarts after the reset protection delay time (trst). When the overcurrent state is released, the operation is automatically released and returns to normal operation.



Timing Chart: RP602xxxxC/D/G/H Reset Protection Circuit

### APPLICATION INFORMATION



**RP602x Typical Application Circuit** 

**Recommended External Components** 

Symbol	Description
C <sub>IN</sub> <sup>(1)</sup>	10 μF, Ceramic, GRM188R60J106ME47, Murata
C <sub>OUT</sub> (2)	22 μF x 2, Ceramic, GRM188R60J226MEA0, Murata
L	1.0 μH, Inductor, DFE201610P- 1R0M, TOKO 1.0 μH, Inductor, XAL4020- 102ME, Coilcraft

#### **Technical Notes on External Components Selection**

- Use ceramic capacitors having a low equivalent series resistance (ESR). Cout should be paralleled with another Cout. When selecting the capacitors, consider the bias characteristics and input/output voltage.
- When the built-in switches are turned off, the inductor may generate a spike-shaped high voltage. Use the high-breakdown voltage capacitor (Cout) which output voltage is 1.5 times or more than the set output voltage.
- Use an inductor that has a low DC resistance, has an enough tolerable current and is less likely to cause magnetic saturation. If the inductance value is extremely small, the peak current of LX may increase. When the peak current of LX reaches to the LX limit current (I<sub>LXLIM</sub>), overcurrent protection circuit starts to operate. When selecting the inductor, consider the peak current of LX pin (I<sub>LXMAX</sub>). Refer to Calculation Method of Peak Current of LX Pin (I<sub>LXMAX</sub>) in Continuous Mode for details.

 $<sup>^{(1)}</sup>$  Place  $C_{\text{IN}}$  as close as possible to the PV $_{\text{IN}}$  pin.

<sup>(2)</sup> Place Cout as close as possible to the Vout pin.

#### Calculation Method of Peak Current of LX Pin (I<sub>LXMAX</sub>) in Continuous Mode

The peak current of LX pin (I<sub>LXMAX</sub>) can be calculated as follows, in the case of an ideal buck converter operating in steady conditions, using the components listed in *Recommended External Components* of *APPLICATION INFORMATION*.

Ripple Current P-P value is described as I<sub>RP</sub>, ON resistance of Pch. Tr. is described as R<sub>ONP</sub>, ON resistance of Nch. Tr. is described as R<sub>ONP</sub>, and DC resistor of the inductor is described as R<sub>L</sub>.

First, when Pch. Tr. is "ON", the following equation is satisfied.

$$V_{IN} = V_{OUT} + (R_{ONP} + R_L) \times I_{OUT} + L \times I_{RP} / t_{ON}$$
 Equation 1

Second, when Pch. Tr. is "OFF" (Nch. Tr. is "ON"), the following equation is satisfied.

$$L \times I_{RP} / t_{OFF} = R_{ONN} \times I_{OUT} + V_{OUT} + R_{L} \times I_{OUT}$$
 Equation 2

Put Equation 2 into Equation 1 to solve ON duty of Pch. Tr. (Don = ton / (toff + ton)):

$$D_{ON} = (V_{OUT} + R_{ONN} \times I_{OUT} + R_{L} \times I_{OUT}) / (V_{IN} + R_{ONN} \times I_{OUT} - R_{ONP} \times I_{OUT}) ...$$
Equation 3

Ripple Current is described as follows:

$$I_{RP} = (V_{IN} - V_{OUT} - R_{ONP} \times I_{OUT} - R_{L} \times I_{OUT}) \times D_{ON} / fosc / L$$
 Equation 4

Peak current that flows through L, and LX Tr. is described as follows:

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The peak current of LX pin (I<sub>LXMAX</sub>) can be calculated as follows, in the case of an ideal boost converter operating in steady conditions, using the components listed in *Recommended External Components* of *APPLICATION INFORMATION*.

Ripple Current P-P value is described as  $I_{RP}$ , Average inductor current is described as  $I_{LX}$ , ON resistance of Pch. Tr. and ON resistance of Nch. Tr. is described as  $R_{ONP}$  and  $R_{ONN}$  respectively, and DC resistor of the inductor is described as  $R_L$ .

First, when Nch. Tr. is "ON", the following equation is satisfied.

 $L \times I_{RP} / t_{ON} = V_{IN} - (R_L + R_{ONN}) \times I_{LX}$  Equation 6

Second, when Nch. Tr. is "OFF" (Pch. Tr. is "ON"), the following equation is satisfied.

 $L \times I_{RP} / t_{OFF} = V_{OUT} + (R_L + R_{ONP}) \times I_{LX} - V_{IN}$  Equation 7

Put Equation 7 into Equation 6 to solve ON duty of Nch. Tr. (Don = ton / (toff + t ton)):

 $D_{ON} = (V_{OUT} - V_{IN} + R_L \times I_{LX} + R_{ONP} \times I_{LX}) / (V_{OUT} + R_{ONP} \times I_{LX} - R_{ONN} \times I_{LX}) ...$ Equation 8

Ripple Current is described as follows:

 $I_{RP} = (V_{IN} - R_L \times I_{LX} - R_{ONN} \times I_{LX}) \times D_{ON} / f_{OSC} / L$  Equation 9

Peak current that flows through L (I<sub>LMAX</sub>), and LX Tr. is described as follows:

 $I_{LXMAX} = I_{LX} + I_{RP} / 2$  Equation 10

Also, the average peak current (I<sub>OUT</sub> and D<sub>ON</sub>) in the boost circuit is described as follows:

I<sub>LX</sub> = I<sub>OUT</sub> / (1 - D<sub>ON</sub>) ...... Equation 11

# **TECHNICAL NOTES**

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed a rated voltage, a rated current or a rated power. When designing a peripheral circuit, please be fully aware of the following points.

- Place the bypass capacitor (C<sub>IIN</sub>) between the PVIN pin and the GND pin with shortest-distance wiring.
- Place the output capacitor (C<sub>OUT</sub>) between the V<sub>OUT</sub> pin and the GND pin with shortest-distance wiring.
   Connect GND of C<sub>OUT</sub> to the GND pin with shortest-distance wiring.
- Make the GND plane wide.
- Ensure the PVIN and GND lines are firmly connected. A large switching current flows through the PVIN, GND, inductor, BOLX, BULX and V<sub>OUT</sub> lines. If their impedance is too high, noise pickup or unstable operation may result.
- Connect the BOLX pin and the inductor and the BULX pin with shortest-distance wiring.

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#### **PCB LAYOUT CONSIDERATIONS**

#### **Current Paths on PCB**

Figure 1 and Figure 2 show the current pathways of step-up circuit when NMOSFET is turned on. Figure 3 and Figure 4 show the current pathways of step-down circuit when PMOSFET is turned on.

The currents flow in the directions of blue or green arrows. The parasitic components, such as impedance, inductance or capacitance, formed in the pathways indicated by the red arrows affect the stability of the system and become the cause of noise. Reduce the parasitic components as much as possible. The current pathways should be made by short and thick wirings.

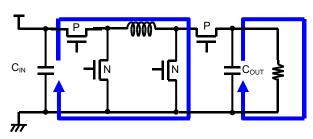


Figure 1. NMOSFET-ON (Step-up)

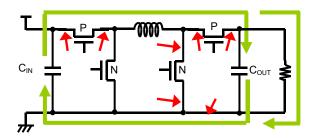


Figure 2. PMOSFET-ON (Step-up)

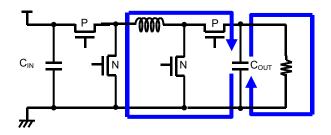


Figure 3. NMOSFET-ON (Step-down)

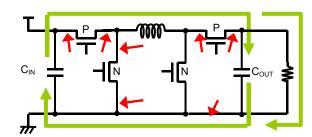
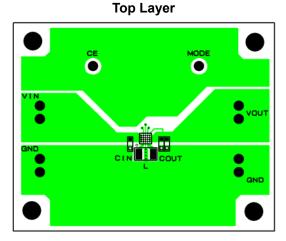
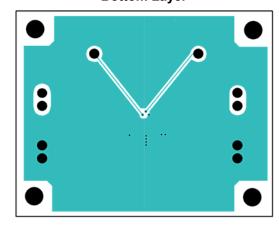


Figure 4. PMOSFET-ON (Step-down)

# **PCB LAYOUT**

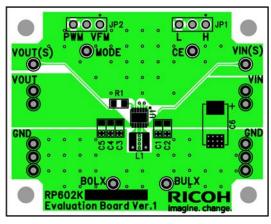


**Bottom Layer** 

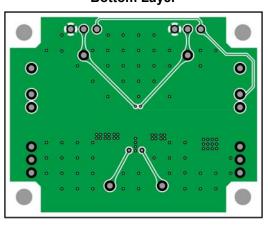


RP602x [PKG: WLCSP-20-P1] PCB Layout

**Top Layer** 



**Bottom Layer** 



RP602x [PKG: DFN(PLP)2730-12] PCB Layer

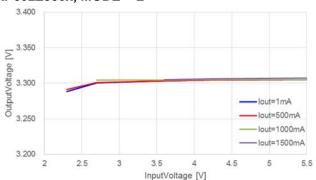
# TYPICAL CHARACTERISTICS

Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

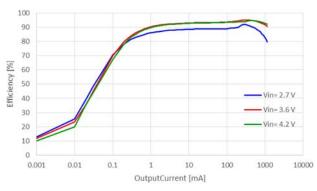
# 1) Input Voltage vs. Output Voltage RP602Z330x, MODE = H

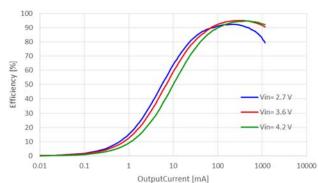


RP602Z330x, MODE = L

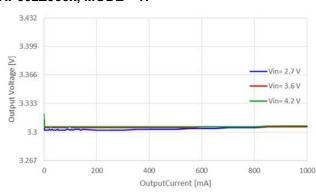


2) Output Current vs. Efficiency (for Different Input Voltages)
RP602Z330x, MODE = H
RP602Z330x, MODE = L

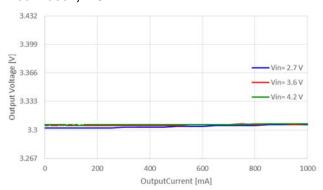




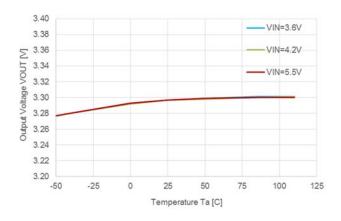
# 3) Output Current vs. Output Voltage RP602Z330x, MODE = H



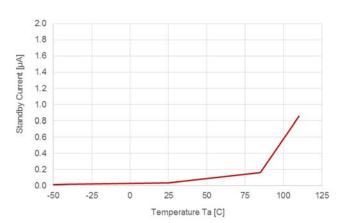
RP602Z330x, MODE = L



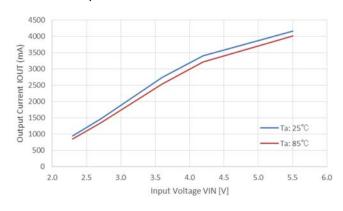
# 4) Temperature vs. Output Voltage RP602Z330x



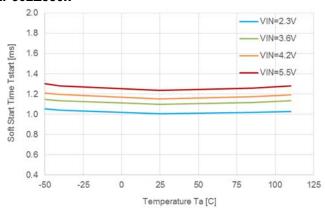
# 5) Temperature vs. Standby Current RP602Z330x, $V_{IN}$ = 5.5 V



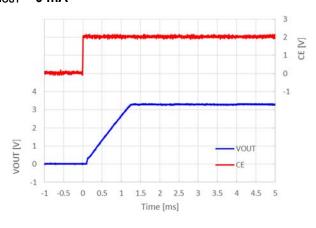
6) Input Voltage vs. Output Current RP602Z330x, MODE = L



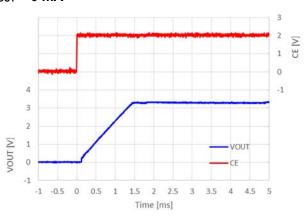
7) Temperature vs. Soft-start Time RP602Z330x



8) CE Start-up Waveform RP602Z330x, V<sub>IN</sub> = 3.6 V, MODE = H I<sub>OUT</sub> = 0 mA

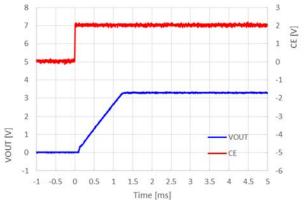


RP602Z330x,  $V_{IN}$  = 5.5 V, MODE = H  $I_{OUT}$  = 0 mA

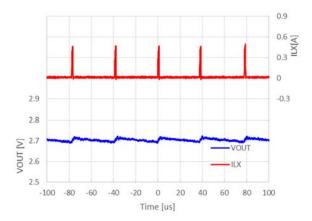


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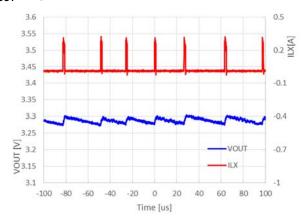
RP602Z330x,  $V_{IN}$  = 3.6 V, MODE = L  $I_{OUT} = 0 mA$ 



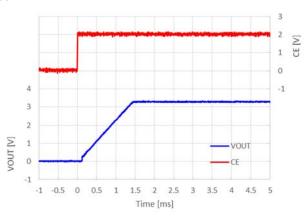
9) Vout Waveform RP602Z270x,  $V_{IN} = 3.6 V$ , MODE = H $I_{OUT} = 10 \text{ mA}$ 



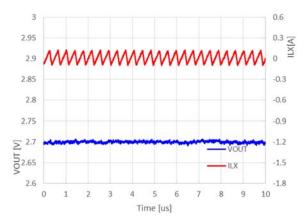
RP602Z330x,  $V_{IN} = 3.6 V$ , MODE = H $I_{OUT} = 10 \text{ mA}$ 



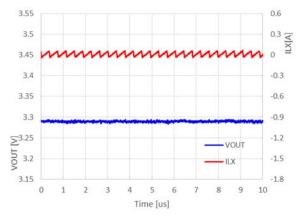
RP602Z330x,  $V_{IN} = 5.5 V$ , MODE = L $I_{OUT} = 0 mA$ 



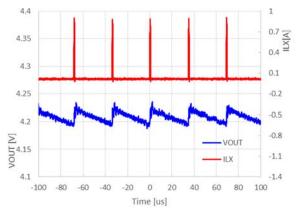
RP602Z270x,  $V_{IN} = 3.6 V$ , MODE = L $I_{OUT} = 0 mA$ 



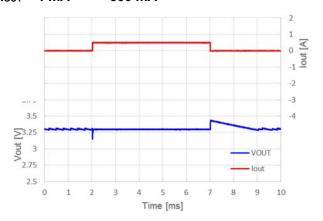
RP602Z330x,  $V_{IN} = 3.6 V$ , MODE = L $I_{OUT} = 0 mA$ 



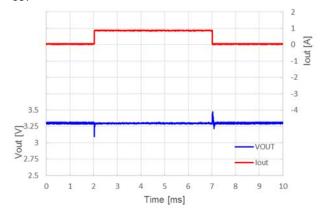
RP602Z420x,  $V_{IN} = 3.6 V$ , MODE = H $I_{OUT} = 10 \text{ mA}$ 



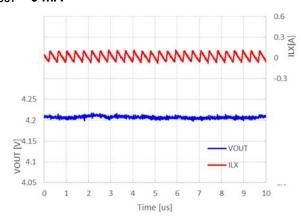
10) Load Transient Response Waveform RP602Z330x, V<sub>IN</sub> = 3.6 V, MODE = H I<sub>OUT</sub> = 1 mA ←→ 500 mA



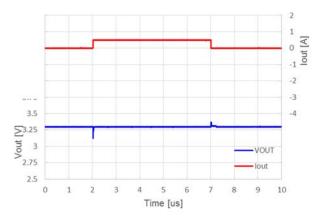
RP602Z330x,  $V_{IN}$  = 3.6 V, MODE = H  $I_{OUT}$  = 50 mA  $\longleftrightarrow$  900 mA



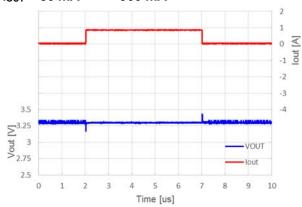
RP602Z420x,  $V_{IN}$  = 3.6 V, MODE = L  $I_{OUT}$  = 0 mA



RP602Z330x,  $V_{IN}$  = 3.6 V, MODE = L  $I_{OUT}$  = 1 mA  $\longleftrightarrow$  500 mA

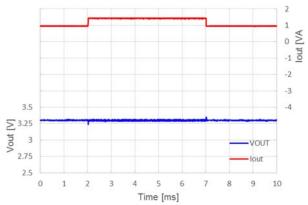


RP602Z330x,  $V_{IN}$  = 3.6 V, MODE = L  $I_{OUT}$  = 50 mA  $\longleftrightarrow$  900 mA

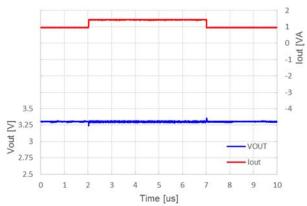


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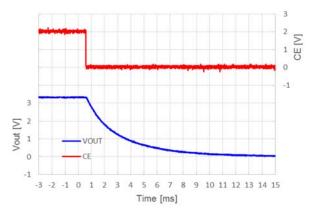
RP602Z330x,  $V_{IN}$  = 3.6 V, MODE = H  $I_{OUT}$  = 1000 mA  $\longleftrightarrow$  1500 mA



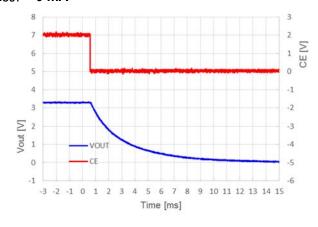
RP602Z330x,  $V_{IN}$  = 3.6 V, MODE = L  $I_{OUT}$  = 1000 mA  $\longleftrightarrow$  1500 mA



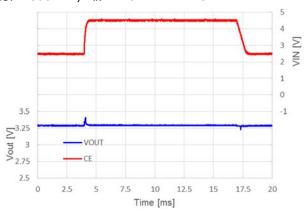
11) CE Turn off Waveform RP602Z330x, V<sub>IN</sub> = 3.6 V, MODE = H I<sub>OUT</sub> = 0 mA



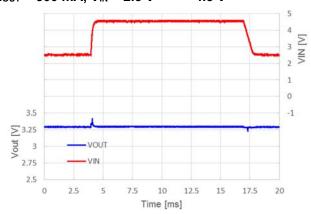
RP602Z330x,  $V_{IN}$  = 3.6 V, MODE = L  $I_{OUT}$  = 0 mA



12) Input Transient Response Waveform RP602Z330x, MODE = H  $I_{OUT}$  = 500 mA,  $V_{IN}$  = 2.5 V  $\longleftrightarrow$  4.5 V



RP602Z330x, MODE = L  $I_{OUT}$  = 500 mA,  $V_{IN}$  = 2.5 V  $\longleftrightarrow$  4.5 V



Ver. B

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-9.

### **Measurement Conditions**

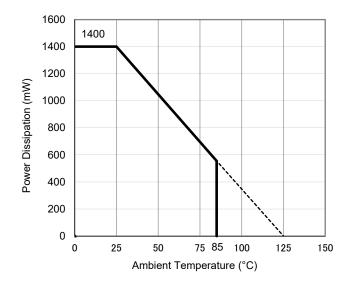
Item	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
Board Dimensions	101.5 mm x 114.5 mm x 1.6 mm	
Copper Ratio	Outer Layers (First and Fourth Layers): 60% Inner Layers (Second and Third Layers): 100%	

#### **Measurement Result**

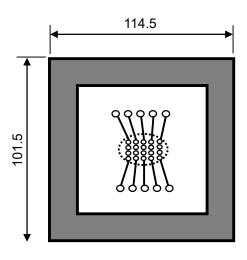
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result	
Power Dissipation	1400 mW	
Thermal Resistance (θja)	θ ja = (125 – 25°C) / 1.4W = 71 °C/W	

 $\theta$ ja: Junction-to-Ambient Thermal Resistance

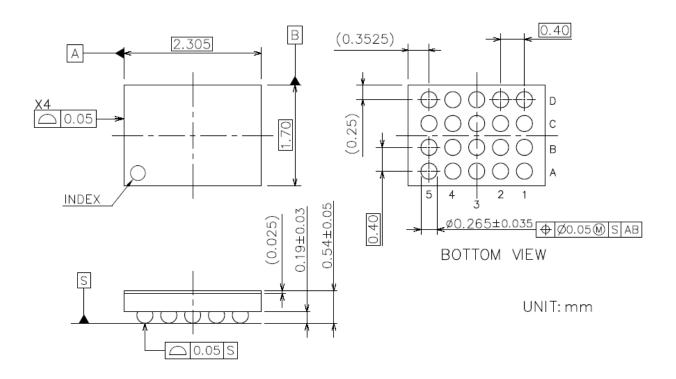


**Power Dissipation vs. Ambient Temperature** 



**Measurement Board Pattern** 

Ver. A



WLCSP-20-P1 Package Dimensions (Unit: mm)

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square	
Through-holes	φ 0.3 mm × 23 pcs	

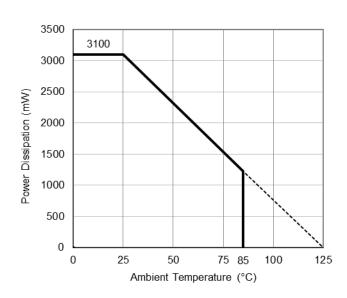
#### **Measurement Result**

(Ta = 25°C, Tjmax = 125°C)

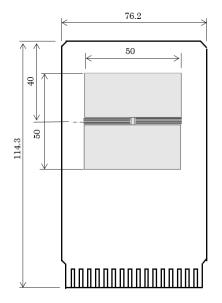
Item	Measurement Result
Power Dissipation	3100 mW
Thermal Resistance (θja)	θja = 32°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 8°C/W

 $\theta$ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter

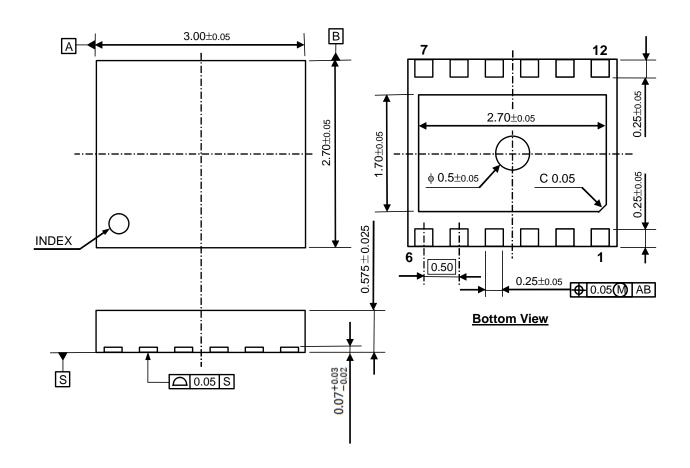


Power Dissipation vs. Ambient Temperature



**Measurement Board Pattern** 

Ver. A



DFN(PLP)2730-12 Package Dimensions (Unit: mm)



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